V10D120C-M3, V10D120CHM3

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RoHS COMPLIANT

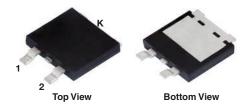
HALOGEN

FREE

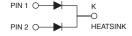
Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.53 \text{ V}$ at $I_F = 2.5 \text{ A}$

TMBS® eSMP® Series TO-263AC (SMPD)



V10D120C



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 5.0 A			
V_{RRM}	120 V			
I _{FSM}	100 A			
V_F at $I_F = 5.0$ A ($T_A = 125$ °C)	0.64 V			
T _J max.	150 °C			
Package	TO-263AC (SMPD)			
Diode variations	Dual common cathode			

FEATURES

- Trench MOS Schottky technology
- · Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, inductrial, and automotive application.

MECHANICAL DATA

Case: TO-263AC (SMPD)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER Maximum repetitive peak reverse voltage		SYMBOL	V10D120C	UNIT V	
		V _{RRM}	120		
Maximum average forward rectified current (fig. 1)	per device		10	^	
	per diode	I _{F(AV)}	5	A	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load		I _{FSM}	100	А	
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150	°C	

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 2.5 A	——— T₁ = 25 °C	V _F ⁽¹⁾	0.61	-	V	
	I _F = 5 A			0.79	0.94		
	I _F = 2.5 A	T _A = 125 °C		0.53	-		
	I _F = 5 A			0.64	0.72		
Reverse current at rated V _R per diode	V _R = 90 V	T _A = 25 °C	I _R ⁽²⁾	2.3	-	μA	
		T _A = 125 °C		2.3	-	mA	
	$V_{\rm P} = 120 {\rm V}$	T _A = 25 °C		-	500	μΑ	
		T _A = 125 °C		5	15	mA	

Notes

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	V10D120C	UNIT
	per diode	- R _{θJC}	3.5	°C/W
Typical thermal resistance	per device		2.5	
	per device	R ₀ JA (1)(2)	48	

Notes

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

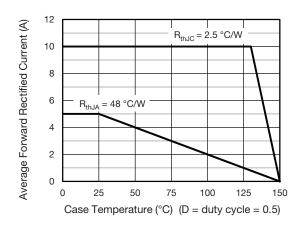
(2) Free air, without heatsink

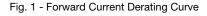
ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AC (SMPD)	V10D120C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel	
TO-263AC (SMPD)	V10D120CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel	

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





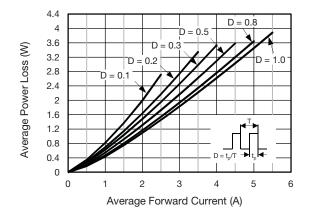


Fig. 2 - Forward Power Loss Characteristics Per Diode

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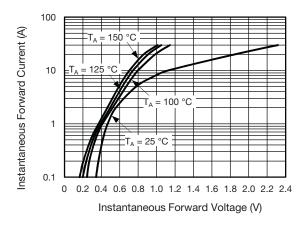


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

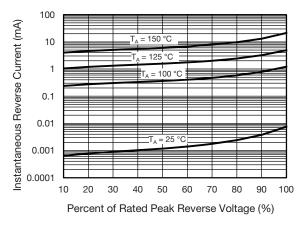


Fig. 4 - Typical Reverse Characteristics Per Diode

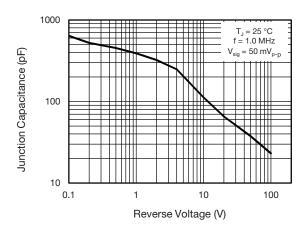


Fig. 5 - Typical Junction Capacitance Per Diode

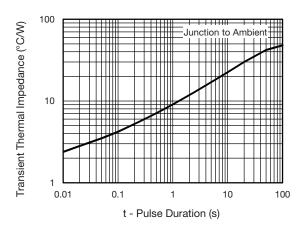


Fig. 6 - Typical Transient Thermal Impedance Per Device

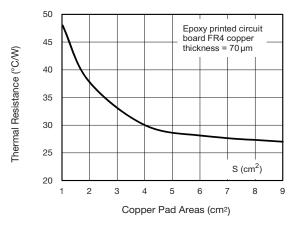
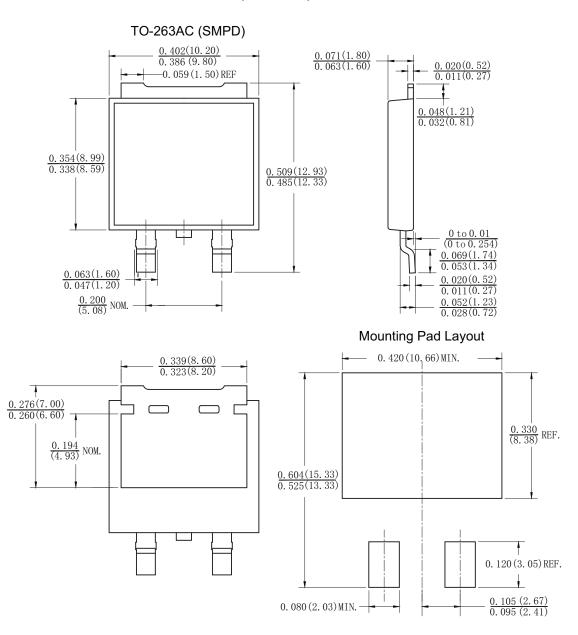


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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